Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L26	70	gariboldi-roberto.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/11 12:11
L27	12	("3727107" | "3805090" | "4058760" | "4322634" | "4327368" | "4477737" | "4551687" | "4695751" | "4740719" | "4804861" | "4987327" | "4996446").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/11 12:22
L28	2	("5182470").URPN.	USPAT	OR	ON	2006/01/11 12:27
L29	5	("3173078" | "4254372" | "4495536" | "4782280").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/11 12:32
L30	8	("5119263").URPN.	USPAT	OR	ON	2006/01/11 13:12
L31	1	(positive adj overvoltage) same (negative adj overvoltage) same output same parasit$3	USPAT	OR	ON	2006/01/11 13:14
L32	61	overvoltage same output same parasit$3	USPAT	OR	ON	2006/01/11 13:14
L33	27	(overvoltage with output) same parasit$3	USPAT	OR	ON	2006/01/11 13:15
S1	502	361/90.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 13:57
S2	196762	protect$3 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 14:11
S3	112	S2 and S1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 13:58
S4	2752	S2 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 13:59
S5	6	S4 and S1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:25
S6	120	S4 same (overvoltage undervoltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:26
S7	36	S6 same output	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:26
S8	342	(undervoltage overvoltage) same protect$3 same output same (semiconductor substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:44

S9	19	S8 same parasit$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:42
S10	2	("4340922").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/03 17:42
S11	229	(undervoltage overvoltage) same protect$3 same output same $3fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:44
S12	39	S8 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S13	502	361/90.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S14	196762	protect$3 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S15	2752	S14 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S16	6	S15 and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S17	120	S15 same (overvoltage undervoltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S18	36	S17 same output	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:45
S19	30	S12 not S16 not S18 not S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 17:46

S20	12528	substrate with parasit$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 14:12
S21	5697	S20 same (conduct$3 connect$3 coupl$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 14:14
S22	3509	S20 with (conduct$3 connect$3 coupl$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 14:15
S23	1335	S22 with (ground power supply potential voltage rail vcc vdd vss vc vd vs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:31
S24	2442595	protect$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:32
S25	12528	substrate with parasit$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:31
S26	3509	S25 with (conduct$3 connect$3 coupl$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:31
S27	1335	S26 with (ground power supply potential voltage rail vcc vdd vss vc vd vs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:31
S28	575	S24 and S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:31
S29	13042	protect$3 with (overvoltage undervoltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:33
S30	31	S27 and S29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:34

S31	196973	protect$3 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:34
S33	246	S27 and S31	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:34
S34	1999	S29 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:34
S35	11	S27 and S34	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:34
S36	31	S30 or S35	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S38	502	361/90.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S39	196973	protect$3 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S40	2757	S39 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S41	6	S40 and S38	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S42	120	S40 same (overvoltage undervoltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S43	36	S42 same output	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36

S44	342	(undervoltage overvoltage) same protect$3 same output same (semiconductor substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S45	19	S44 same parasit$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S46	39	S44 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S47	502	361/90.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S48	196973	protect$3 same (resistance impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S49	2757	S48 same $4fet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S50	6	S49 and S47	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S51	120	S49 same (overvoltage undervoltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S52	36	S51 same output	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S53	30	S46 not S50 not S52 not S45	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/10 15:36
S54	27	S36 not S41 not S43 not S45 not S53	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/11 12:11

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	893626	protect$5	USPAT	OR	OFF	2006/01/11 14:00
L2	25084	1 same (pn diode)	USPAT	OR	OFF	2006/01/11 14:01
L3	996	2 same parasit$6	USPAT	OR	OFF	2006/01/11 14:02
L4	195	3 same potential	USPAT	OR	OFF	2006/01/11 14:03
L5	89	4 same substrate	USPAT	OR	OFF	2006/01/11 14:06
L6	4	5 same polar$8	USPAT	OR	OFF	2006/01/11 14:19
L7	26	5 same rever$8	USPAT	OR	OFF	2006/01/11 14:19